



#### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>A</sub> = +25°C
	710mΩ @ V <sub>GS</sub> = -4.5V	-0.63A
-20V	930mΩ @ V <sub>GS</sub> = -2.5V	-0.55A
	1250mΩ @ V <sub>GS</sub> = -1.8V	-0.48A

#### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP21D1UTQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- DC-DC converters
- Load switches
- Power-management functions

#### **Mechanical Data**

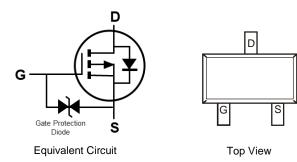
- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





SOT523

Top View



#### Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMP21D1UTQ-7	SOT523	3000	Tape & Reel	
DMP21D1UTQ-13	SOT523	10000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

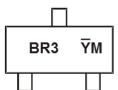
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



BR3 = Product Type Marking Code  $\overline{Y}M = Date Code Marking$ Y or  $\overline{Y} = Year (ex: K = 2023)$ M = Month (ex: 9 = September)

Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	20231	2032	2033	2034
Code	К	L	М	Ν	Р	R	S	Т	U	V	W	Х
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	-20	V
Gate-Source Voltage	V <sub>GSS</sub> ±8		V	
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$ State $T_A = +25^{\circ}C$ $T_A = +75^{\circ}C$		ID	-0.63 -0.51	A
Maximum Continuous Body Diode Forward Currer	nt (Note 5)	ls	-0.4	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)	ldм	-2.5	А

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	Steady State	PD	0.26	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	480	°C/W
Total Power Dissipation (Note 5)	Steady State	PD	0.44	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	287	°C/W
Operating and Storage Temperature Range		TJ, T <sub>STG</sub>	-55 to +150	°C

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



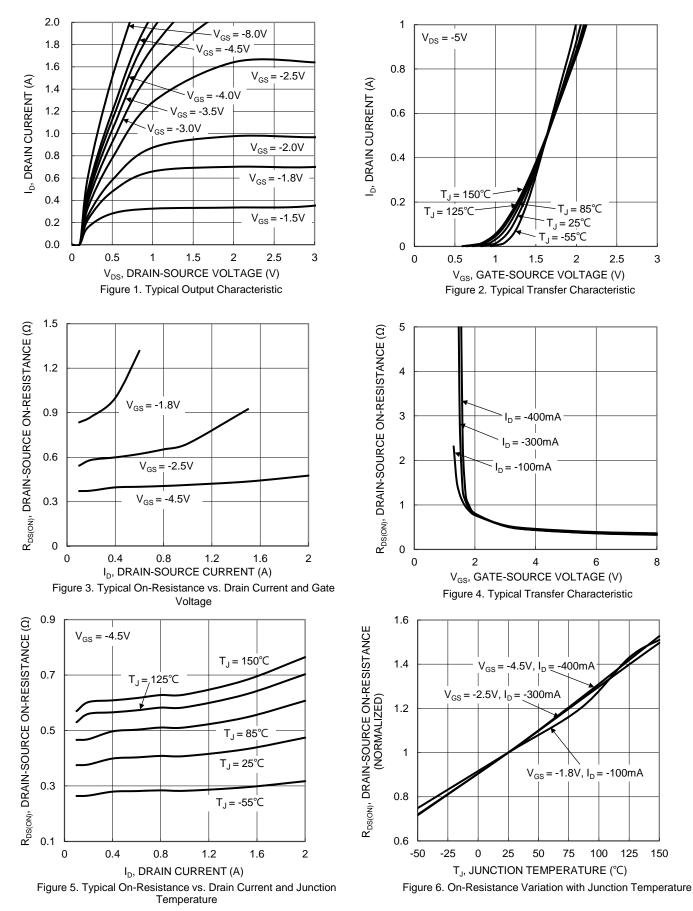
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Cymbol	WIIII	ιyp	Max	Unit	Test condition
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20		_	V	Vgs = 0V, Ip = -250µA
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	_		-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	lgss		_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	-0.5		-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
			390	710		$V_{GS} = -4.5V, I_D = -400mA$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	590	930	mΩ	$V_{GS} = -2.5V, I_D = -300mA$
		_	770	1250		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -100mA
Diode Forward Voltage (Note 7)	Vsd	_	-0.8	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -300mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	33	—	pF	
Output Capacitance	Coss	_	10	—	pF	VDS = -10V, VGS = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	3	—	pF	
Total Gate Charge	Qg	_	1.4	—	nC	
Gate-Source Charge	Qgs	_	0.5	—	nC	VGS = -4.5V, VDS = -15V
Gate-Drain Charge	Q <sub>gd</sub>		0.1	_	nC	אוי = עוך = עוך
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.6	_	ns	
Turn-On Rise Time	tR		2.2	_	ns	V <sub>DS</sub> = -10V, I <sub>D</sub> = -1A
Turn-Off Delay Time	tD(OFF)		14.4	_	ns	$V_{GS}$ = -4.5V, $R_G$ = 6 $\Omega$
Turn-Off Fall Time	tF		7.9	_	ns	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

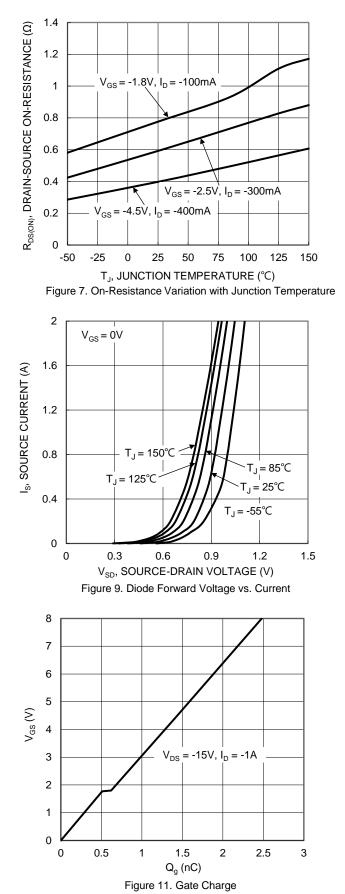


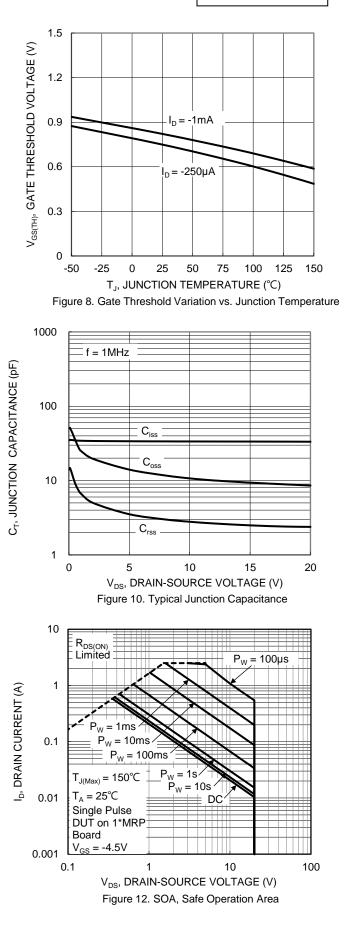
## DMP21D1UTQ



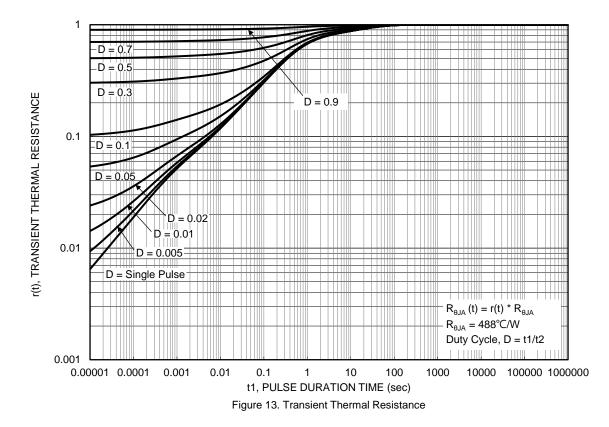


### DMP21D1UTQ





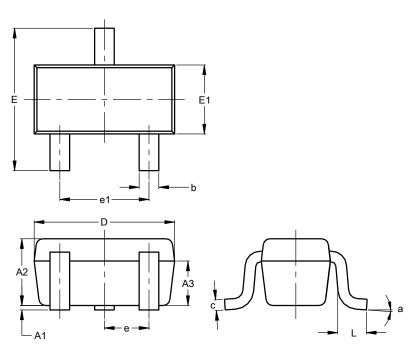






#### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

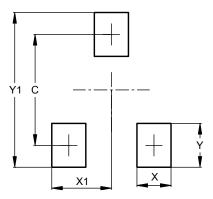


		TEOD								
	SOT523									
Dim	Min	Max	Тур							
A1	0.00	0.10	0.05							
A2	0.60	0.80	0.75							
A3	0.45	0.65	0.50							
b	0.15	0.30	0.22							
С	0.10	0.20	0.12							
D	1.50	1.70	1.60							
ш	1.45	1.75	1.60							
E1	0.75	0.85	0.80							
e		0.50 BS	С							
e1	0.90	1.10	1.00							
L	0.20	0.40	0.33							
а	0°		8°							
Α	I Dimen	sions ir	n mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

# SOT523



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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